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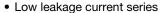
Vishay Semiconductors

# Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



DO-5 (DO-203AB)

#### **FEATURES**





Good surge current capability up to 1000 A

RoHS

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

A, 40 A, 60 A
-5 (DO-203AB)
Single

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
1		35 <sup>(1)</sup>	35 <sup>(1)</sup>	40 <sup>(1)</sup>	60 <sup>(1)</sup>	Α
I <sub>F(AV)</sub>	T <sub>C</sub>	140 <sup>(1)</sup>	140 <sup>(1)</sup>	150 <sup>(1)</sup>	140 <sup>(1)</sup>	°C
1	50 Hz	480	380	765	860	^
I <sub>FSM</sub>	60 Hz	500 <sup>(1)</sup>	400 <sup>(1)</sup>	800 <sup>(1)</sup>	900 (1)	Α
I <sup>2</sup> t	50 Hz	1140	730	2900	3700	A <sup>2</sup> s
1-1	60 Hz	1040	670	2650	3400	A-S
I <sup>2</sup> √t		16 100	10 300	41 000	52 500	A <sup>2</sup> √s
V <sub>RRM</sub>	Range	50 to 600 <sup>(1)</sup>	700 to 1000 <sup>(1)</sup>	50 to 600 <sup>(1)</sup>	50 to 600 <sup>(1)</sup>	V
TJ		-65 to +200	-65 to +200	-65 to +200	-65 to +200	°C

#### Note

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	3		V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> ) V	$V_{RM}$ , MAXIMUM DIRECT REVERSE VOLTAGE (T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> ) V		
VS-1N1183	VS-1N1183A	VS-1N2128A	50 <sup>(1)</sup>	50 <sup>(1)</sup>		
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 (1)		
VS-1N1185	VS-1N1185A	VS-1N2130A	150 <sup>(1)</sup>	150 <sup>(1)</sup>		
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)		
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 <sup>(1)</sup>		
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)		
VS-1N1189	VS-1N1189A	VS-1N2137A	500 <sup>(1)</sup>	500 <sup>(1)</sup>		
VS-1N1190	VS-1N1190A	VS-1N2138A	600 <sup>(1)</sup>	600 <sup>(1)</sup>		
VS-1N3765	VS-1N2160		700 (1)	700 <sup>(1)</sup>		
VS-1N3766			800 (1)	800 (1)		
VS-1N3767			900 (1)	900 (1)		
VS-1N3768			1000 (1)	1000 (1)		

#### Notes

<sup>(1)</sup> JEDEC® registered values

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA
 JEDEC® registered values

 $<sup>^{(2)}</sup>$  For 1N1183 Series and 1N3765 Series  $T_C$  = -65  $^{\circ}$ C to +190  $^{\circ}$ C



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PARAMETER		SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current at case temperature		I <sub>F(AV)</sub>	1-phase operation, 180° sinusoidal conduction		35 <sup>(1)</sup> 140 <sup>(1)</sup>	35 <sup>(1)</sup>	40 <sup>(1)</sup> 150 <sup>(1)</sup>	60 <sup>(1)</sup>	A °C
Maximum peak one cycle non-repetitive surge current		I <sub>FSM</sub>	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	480	380	765	860	A
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		500 <sup>(1)</sup>	400 (1)	800 (1)	900 (1)	
			Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with ½ V <sub>RRM</sub> applied following surge = 0	570	455	910	1000	
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		595	475	950	1050	
Maximum I <sup>2</sup> t for fusing			t = 10 ms With rated V <sub>RRM</sub>	1140	730	2900	3700		
		- l <sup>2</sup> t	t = 8.3 ms	applied following surge, initial $T_J = T_J$ maximum	1040	670	2650	3400	A <sup>2</sup> s
Maximum I <sup>2</sup> t for individual device fusing			t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = T_J$ maximum	1610	1030	4150	5250	
			t = 8.3 ms		1470	940	3750	4750	
Maximum I <sup>2</sup> √t for individual device fusing		<b>I</b> 2√t (2)	t = 0.1 to 10 ms, V <sub>RRM</sub> = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage at maximum forward current (I <sub>FM</sub> )		V <sub>FM</sub>	T <sub>J</sub> = 25 °C		1.7 <sup>(1)</sup>	1.8 <sup>(1)</sup>	1.3 <sup>(1)</sup>	1.3 <sup>(1)</sup>	V
					110	110	126	188	Α
_	$V_{RRM} = 700$				-	5.0 <sup>(1)</sup>	-	-	
Maximum average	$V_{RRM} = 800$		Maximum rated I <sub>F0</sub>	<sub>AV)</sub> and T <sub>C</sub>	-	4.0 (1)	-	-	
reverse current	$V_{RRM} = 900$	I <sub>R(AV)</sub>	The state of the s		-	3.0 (1)	-	-	mA
	V <sub>RRM</sub> = 1000				-	2.0 (1)	-	-	
			Maximum rated I <sub>F(x</sub>	10 <sup>(1)</sup>	-	2.5 <sup>(1)</sup>	10 <sup>(1)</sup>		

#### Notes

(1) JEDEC® registered values

(2)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$ 

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum operating case temperature range	T <sub>C</sub>	-65 to +190 <sup>(1)</sup> -65		-65 to	+200	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-65 to +175 <sup>(1)</sup> -65 t		-65 to	+200	
Maximum internal thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	1.0	1.00 (1)		0.65 (1)	°C/W
Thermal resistance, case to sink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.25			C/VV	
		Not lubricated thread, tighting on nut (2)		3.4	4 (30)		
Maximum allowable		Lubricated thread, tighting on nut (2)		2.	3 (20)		N·m
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2 (37)			(lbf · in)	
( , . , , . ,		Lubricated thread, tighting on hexagon (3)		3.5	2 (28)		
Aiii					17		g
Approximate weight					0.6		oz.
Case style	style JEDEC® DO-5 (DO-203AB)		AB)	•			

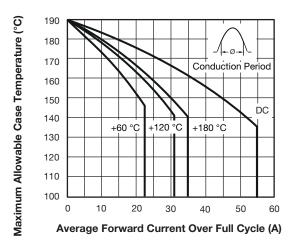
#### Notes

(1) JEDEC registered values®

(2) Recommended for pass-through holes

(3) Recommended for holed threaded heatsinks

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Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

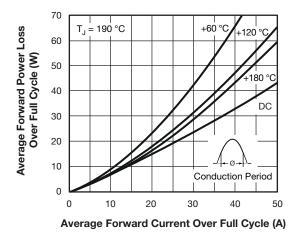


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

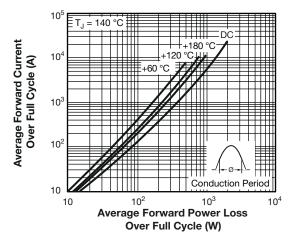


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

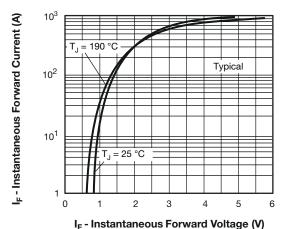


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

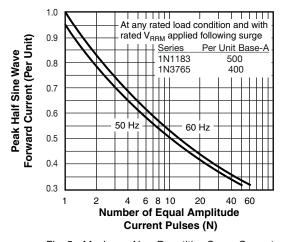
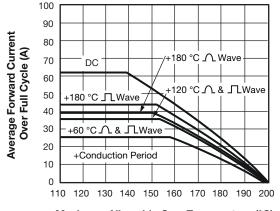


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



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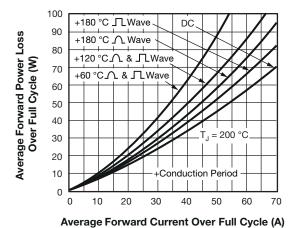


Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

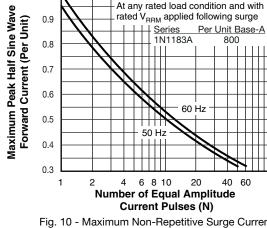
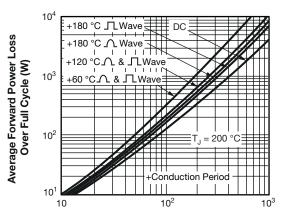


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

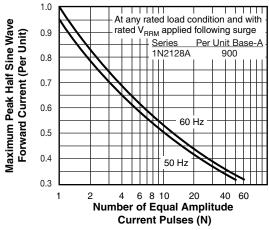


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series

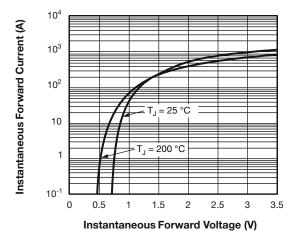


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

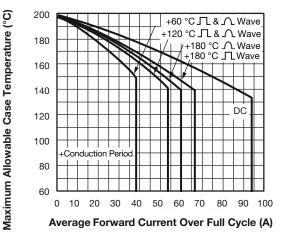


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

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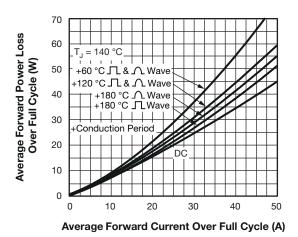
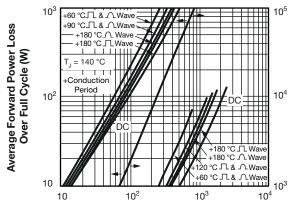


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

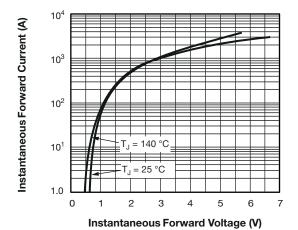


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

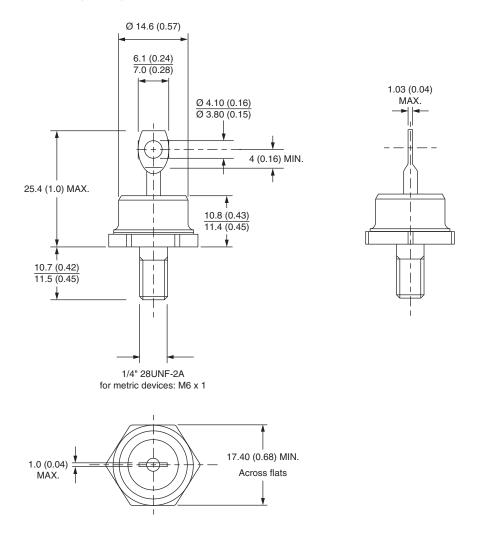
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95360			



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# DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

**DIMENSIONS** in millimeters (inches)





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